

# Commissioning the CMS Pixel detector with cosmic ray data

#### V.Chiochia

University of Zürich - Physik Institut On behalf of the CMS Pixel group 14<sup>th</sup> RD50 Workshop 3-5 June, 2009 - Freiburg, Germany

V. Chiochia (Uni. Zürich) - Commissioning the CMS pixel detector, RD50 Workshop, Freiburg, Germany

# Outline



- Detector layout and installation
- First results from cosmic ray data:
  - Thresholds and charge collection
  - Lorentz angle and position resolution
- Performance after irradiation from test-beam measurements:
  - Charge collection and cluster multiplicity
  - Position resolution

### **Detector layout**



- Three barrel layers and two endcap disks at each barrel end
  - Barrel layers at 4 cm, 7 cm, and 11 cm radius
  - ~700 modules made of 16 chips in barrel region (67k channels/module)
  - Endcap disks: 24 blades made of 7 sensors (4 or 3 per side)
  - About 67x10<sup>6</sup> channels in total, L~1 m, R~30 cm

#### Sensors and front-end electronics:

- "n-in-n" design with p-spray (CiS, barrel) and p-stop (Sintef, endcaps) isolation
- $100(r\phi)x150(z) \ \mu m^2$  pixel cell, charge sharing in 4 T magnetic field
- PSI 0.25 μm CMOS chip with column drain full analogue readout



### **Detector installation**





V. Chiochia (Uni. Zürich) – Commissioning the CMS pixel detector, RD50 Workshop, Freiburg, Germany



### **Pixel thresholds & noise**



• Other sources of electronic noise (e.g. optical transceivers) ~300 electrons

### **Charge collection**



Pixel charge calibrated with pulser signal:

- Converts ADC counts into electrons
- Low charge part fitted with straight line
- 1 VCAL unit ~ 65 electrons





#### Cluster charge after calibration

- Only clusters with charge sharing
- Most probable value ~21'000 electrons
- In agreement with simulation within 5%

#### Lorentz angle



,1 pixel,

 $\otimes_{\mathbf{B}}$ 

- Measured from the minimum of the cluster size vs. impact angle
- Bias=100V, 300V Temp.=20°C
- Compatible with the expectations



track

# **Position resolution**



#### 3.8T field, In-time threshold~5000 electrons





overlap measurement

- Position resolution measured from overlapping sensors in a given layer
- Less sensitive to misalignment and multiple scattering
- Measured values are compatible with the PIXELAV simulation



overlap measurement

## **Performance after irradiation**



#### Sensor performance measured at the CERN H2 beam line with 150 GeV pions

- Fully pixel-based telescope with four planes.
- Final sensor layout (p-spray, 100×150  $\mu$ m<sup>2</sup>) and front-end electronics
- Setup installed in the H2 3T superconducting solenoid
- Sensors irradiated up to 8×10<sup>14</sup> n/cm<sup>2</sup>, standard annealing
- Fluence expected after first four years at 4 cm layer = 6x10<sup>14</sup> n/cm<sup>2</sup>





V. Chiochia (Uni. Zürich) - Commissioning the CMS pixel detector, RD50 Workshop, Freiburg, Germany

### Charge and cluster size



#### Straight tracks, 3T field, Readout threshold ~ 2850 electrons



### **Position resolution**



#### Straight tracks, 3T field, Readout threshold ~ 2850 electrons



- Position resolution degrades by almost a factor 2 at  $\Phi_{eq}=6\times10^{14}$  n/cm<sup>2</sup>
  - Dominated by increase of single-pixel clusters
- Resolution of 2-pixel clusters almost flat vs.  $\Phi_{eq}$

## Summary



CMS pixel detector installed in summer 2008 has been tested with cosmic ray events Charge collection behaves as expected Lorentz angle in barrel section ~25° at (100V, 20°C, 3.8T). To be remeasured this year at 150V and 10°C Position resolution is well described by PIXELAV simulation Performance after irradiation were measured at the H2 beam line with a 3T magnetic field, final sensor, final front-end chip 10 ke<sup>-</sup> cluster charge at  $\Phi$ =8×10<sup>14</sup> n<sub>eg</sub>/cm<sup>2</sup>, 300V ٠ Single pixel clusters become dominant around  $\Phi = 2 \times 10^{14} n_{eq}/cm^2$ RMS of residuals at  $\Phi$ =8×10<sup>14</sup> n<sub>eq</sub>/cm<sup>2</sup> is ~23  $\mu$ m. Unirradiated ~12  $\mu$ m.



## BACKUP

V. Chiochia (Uni. Zürich) – Commissioning the CMS pixel detector, RD50 Workshop, Freiburg, Germany

## **PIXELAV: a sensor simulation**



- In addition to the standard CMSSW full detector simulation a dedicated pixel sensor and front-end simulation was developed
- Electrostatic simulation based on TCAD plus charge creation, drift and signal induction based on custom program PIXELAV.
- Incorporates double-trap effective model of radiation damage. Describes cluster shapes from beam tests in a wide fluence range  $\Phi_{eq}=(0.5-6)x10^{14} \text{ n/cm}^2$
- The simulation is used to extract average cluster shapes, called <u>templates</u>



#### Sensor irradiation: $\Phi$ =6x10<sup>14</sup> n/cm<sup>2</sup>